Silicocene, $(C_5H_5)_2$ Si: A Highly Symmetric Sandwich Compound?

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Abstract: Ab initio quantum mechanical methods are employed in the study of several conformers of silicocene, $(C_5H_5)_2Si$. Specifically, fully optimized structures are obtained for C_s , C_2 , D_{5h} , C_{2v} , and D_{5d} isomers at the self-consistent-field (SCF) level of theory. Three different Gaussian basis sets ranging in size from a minimal STO-3G* basis to one of double-5 plus polarization (DZP) quality were used. The latter set consisted of 210 contracted basis functions. The effects of electron correlation were estimated using second-order perturbation theory (MP2) with the largest basis set. At the SCF DZP level of theory, silicocene is predicted to adopt a low-symmetry bent C, structure. However, the difference in energy between the low-symmetry (C₁, C₂) and C_{2v} conformers is only 2.4 kcal/mol, with the D_{5d} conformer lying 8.8 kcal/mol higher in energy. Electron-correlation effects determined from MP2 energies at the SCF DZP optimized structures favor the higher symmetry species, with a C_{2n} conformer predicted to be 7.5 kcal/mol lower in energy than the C_s/C_2 structures. It is shown that basis set augmentation, particularly the inclusion of polarization functions, favors the higher symmetry species. It is concluded that ab initio studies of π -bonded complexes, or sandwich compounds, require at least a DZP basis set to obtain reliable results. These studies do not conclusively determine the symmetry of the minimum energy conformer of silicocene. However, it is clear that the silicocene potential energy surface is flat with respect to motion of the cyclopentadienyl rings about the silicon atom and that if the high-symmetry D_{5d} or D_{5h} conformer is not a minimum, then it will not be significantly higher in energy than the true gas-phase minimum.

There has been considerable interest in the cyclopentadienyl sandwich compounds, Cp_2M ($Cp = C_5H_5$) since a π -bonded D_{5d} structure was first suggested for ferrocene in 1952.¹ Contrary to the highly symmetric structure adopted by ferrocene, synthesis and structure determination of the group 14 sandwich compounds and the isoelectronic group 15 cations has shown that the majority of these compounds adopt a bent conformation with a subsequent variation in M-C bond distances. The first group 14 cyclopentadienyl sandwich compound to be synthesized was plumbocene in 1956 by Fischer and Grubert.² This compound is now understood to have a polymeric zigzag structure in the solid state with bridging cyclopentadienyl rings.³ However, plumbocene is monomeric in the gas phase, with electron-diffraction measurements determining an angle between ring planes of $45 \pm 15^{\circ}$ and a mean Pb-C distance⁴ of 2.78 Å. Additionally, X-ray analysis of the full methyl derivative $(C_5Me_5)_2Pb$ has determined a ring centroid-Pb-ring centroid angle of 151° with a range of Pb-C distances⁵ from 2.69 to 2.90 Å.

Ascending the periodic table, preliminary electron-diffraction measurements showed stannocene, Cp₂Sn, to be bent with a ring centroid-Sn-ring centroid angle of $\sim 125^{\circ}$ or an angle between ring planes⁴ of $\sim 55^{\circ}$. Later, X-ray analysis determined this compound to be monomeric in the solid phase with two bent structures present in the crystal.⁵ These structures were determined to have ring centroid-Sn-ring centroid angles⁵ of 148.0° and 143.7° or, alternatively, angles between ring planes⁶ of 45.9° and 48.4°. The analysis determined Sn-C distances of 2.58-2.75 and 2.56-2.85 Å, respectively. Electron-diffraction measurements on $(C_5H_4Me)_2Sn$ show that this compound is also bent with an angle between ring planes of $50 \pm 6^{\circ.6}$ An X-ray analysis of the fully methyl derivative, (C₅Me₅)₂Sn, gives two conformers with angles between ring planes of 36.4° and 35.4° and a corresponding range of Sn-C distances⁷ of 2.57-2.78 and 2.56-2.85 Å. As noted by Almlöf et al.,⁶ full methyl substitution favors a less bent structure as one would expect from consideration of steric effects. It is interesting to note that, although the angle between ring planes is decreased by full methyl substitution, the variation in Sn-C bond distances is virtually unaffected. Larger substituent groups on the cyclopentadienyl rings give a highly symmetric structure for decaphenyl stannocene,⁸ which has five equivalent Sn-C bonds

to each ring (Sn-C = 2.689 Å) and a ring centroid-Sn-ring centroid angle of 180.0°

Germanocene, $(C_5H_5)_2$ Ge, was first synthesized in 1973 by Scibelli and Curtis.⁹ The gas-phase structure of the unsubstituted molecule has not yet been determined, but the gas electron-diffraction (GED) structure of the dimethyl derivative $(C_5H_4Me)_2Ge$ shows this compound to have an angle between ring planes⁶ of $34 \pm 7^{\circ}$. X-ray studies of the unsubstituted parent molecule have determined a bent structure in the crystal with an angle between ring planes of 50.4° and a range of Ge-C distances¹⁰ from 2.347 to 2.730 Å. Note that the parent germanocene exhibits a larger deviation from a parallel $(D_{5d} \text{ or } D_{5h})$ structure than does stannocene. The full methyl derivative (C5Me5)2Ge has been synthesized,⁷ but as yet no structural determination has been made.

The valence isoelectronic group 15 cations, $(C_5Me_5)_2As^+$ and $(C_5Me_5)_2Bi^+$ have been synthesized with an X-ray structural analysis having been reported for the arsenic compound.¹¹ This C, symmetry cation is bent with an angle between ring planes of 36.5° and more significantly has a large range of As-C bond distances. The As-C distances vary from 2.188 to 2.667 Å in one cyclopentadienyl ring and from 2.261 to 2.742 Å in the second ring. Thus, this molecule can no longer be described as exhibiting bis- η^5 or η^5 bonding (i.e. five equivalent M-C bonds) but rather η bonding to the first ring and η^2 to the second.

In light of these observations it was interesting to note the recent synthesis and structural determination¹² of decamethyl silicocene,

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 $(C_5Me_5)_2Si$. This is the lightest of the group 14 sandwich compounds to be synthesized and, unlike decamethyl germanocene, $(C_5Me_5)_2Si$ adopts a highly symmetric D_{5d} structure (angle between rings of 0°) in the crystal. A second conformer, attributed by Jutzi, Kanne, and Krüger¹² to arise from crystal-packing effects, was found to have an angle between ring planes of 25.3° with an associated range of Si-C distances from 2.324 to 2.541 Å.

This result was surprising since most of the previous group 15 dicyclopentadienyl sandwich compounds were found to adopt lower symmetry, bent conformations. Furthermore, an ab initio theoretical study of the valence isoelectronic phosphocenium cation, $(C_5H_5)_2P^+$, predicted the minimum energy conformation to have C_s symmetry, similar to the experimentally observed (C_5Me_5)₂As⁺ compound. Moreover, the results of the unsubstituted group 15 compounds indicate that as the central atom becomes smaller (i.e., $Pb \rightarrow Sn \rightarrow Ge$), the angle between the Cp rings increases. Therefore, it is uncertain whether $(C_5H_5)_2S_1$ will also exhibit parallel Cp rings since $(C_5 Me_5)_2 Si$ may adopt D_{5d} symmetry due solely to steric effects.

The aim of this study was to determine the structure and energetics of the different conformers of the parent silicocene, $(C_5H_5)_2$ Si, using ab initio theoretical methods. Previously, the ab initio self-consistent-field (SCF) method has been applied to the unsubstituted germanocene,⁶ but the structure was not fully optimized. As already noted, the structure and energetics of several conformers of the isoelectronic cation, $(C_5H_5)_2P^+$, were determined from full-geometry optimization using ab initio techniques.¹³ Phosphocenium was predicted to have a global minimum energy structure of C, symmetry with η^2 bonding to one ring and η (or η^3) bonding to the other, which is consistent with the results determined experimentally for the $(C_5Me_5)_2As^+$ cation. Two studies have reported MNDO results of silicocene.^{14,15} These two studies are at odds with the first reporting a global minimum of D_{5h} symmetry, and the second, reporting a C_{2n} minimum structure. However, the second¹⁵ study performed a more rigorous search of the silicocene potential energy surface. They found that the lower symmetry structure was favored by \sim 5.3 kcal/mol over the D_{5d} structure using a constrained search for the low-symmetry species.

In the interest of quality, we decided to determine rigorously the structures of the D_{5d} , D_{5h} , C_{2v} , C_s , and C_2 conformers of silicocene, optimizing all variables within these symmetry constraints and categorizing the nature of the potential energy surface stationary point from analysis of the Hessian. The six silicocene conformers included in this study encompass all different reported equilibrium structures of the group 14 dicyclopentadienyl compounds and the isoelectronic group 15 cations. A description of each conformer will be given in the next section together with the full details of the theoretical approach. A discussion of the energetics of the six silicocene conformers and a discussion of the equilibrium structures are presented. The bonding present in the six conformers of silicocene is also discussed, followed by our concluding remarks.

Theoretical Approach

Six conformers of silicocene were optimized at the SCF level of theory within the given symmetry constraints. An analytic gradient method was employed, and the structures were optimized such that all Cartesian gradients were less than 10⁻⁵ au. The six models were chosen as follows:

(1) This is a D_{5d} structure, which was investigated because the experimental information on decamethyl silicocene, indicated that the D_{5d} structure was present in the crystal.¹² This conformer has the two Cp rings staggered. This conformer will be referred to as the D_{5d} structure.

(2) This is a D_{5h} structure, which an MNDO study¹⁵ predicted to be of comparable energy to the D_{5d} structure. The Cp rings are eclipsed in this conformer. This conformer will be referred to as the D_{5h} structure.

(3) This is designated a "point-to-edge" structure using the notation of ref 13 since the two Cp rings approach most closely via a single carbon atom on one ring and two equivalent carbon atoms on the other ring. This conformer has only one plane of symmetry (C_s) and the bonding to each Cp ring is inequivalent. This structure would result from relaxation of the parallel Cp rings in the D_{5d} conformer. It is analogous to the lowest energy conformer reported for the isoelectronic $(C_5H_5)_2P^+$ cation¹³ and to the experimentally observed¹¹ (C_5Me_5)₂As⁺. This conformer will be referred to as the C_s structure.

(4) This structure has a 2-fold rotation axis (i.e., C_2 symmetry), so that the bonding to the two Cp rings is equivalent. This type of structure was found to be the second lowest energy conformer¹³ of $(C_5H_5)_2P^+$. This conformer will be referred to as the C_2 structure.

(5) This is a C_{2v} structure, labeled "edge-to-edge" since the two rings approach most closely via a C-C bond on each ring. This conformer will be referred to as the $C_{2\nu}(e-e)$ structure.

(6) This is a C_{2v} structure, labeled "point-to-point" since the two rings approach most closely via a unique carbon atom on each ring. The latter two conformers, $C_{2\nu}(e-e)$ and $C_{2\nu}(p-p)$ were studied since these structures result from relaxation of the parallel Cp rings in the D_{5h} species. This conformer will be referred to as the $C_{2\nu}(p-p)$ structure.

The structures were first optimized using an STO-3G basis set16 augmented by a set of d functions on the central atom ($\alpha_d(Si) = 0.5$). This basis is designated STO-3G*. Such basis sets are known to give improved structures, compared to experiment when considering secondrow atoms,¹⁷ than are their STO-3G counterparts. When the structural parameters and the associated analytic Hessians are used as a starting point, the conformers were then optimized with a double ζ -basis,¹⁸⁻²⁰ again augmented by a d function of exponent 0.5 on the central atom. This contracted basis, Si(11s7p1d/6s4p1d), C(9s5p/4s2p), H(4s/2s), is denoted DZd. Finally, to measure the importance of polarization functions on the orientation of the cyclopentadienyl rings, structures 1, 3, and 4 were optimized with the above double ζ -basis, but now incorporating one set of polarization functions on carbon ($\alpha_d(C) = 0.85$) and two sets of polarization functions on silicon ($\alpha_d(Si) = 0.75$; $\alpha_d(Si) = 0.25$). This basis set, Si(11s7p2d/6s4p2d), C(9s5p1d/4s2p1d), H(4s/2s) which includes 210 contracted Gaussian basis functions, is denoted DZP.

It is particularly important to use a large flexible basis set of at least DZP quality since there are several recent examples²¹⁻²⁶ for silicon compounds in which the ground-state structure was incorrectly predicted with smaller basis sets. In some of these studies²³⁻²⁵ it has been demonstrated that more than one set of d polarization functions are necessary for the silicon atom. Furthermore, it is reasonable to expect that carbon d polarization functions will be very important in the description of a bis η^5 bonded sandwich compound. Therefore, on the basis of the flexibility of the DZP basis, we expect it to yield the most reliable results.

Analytic second derivatives were used to obtain the harmonic frequencies and infrared intensities for each basis set. Analytic methods are essential for such molecules, when considering both the number of atoms and the weak binding of the central atom to the Cp rings where real vibrational frequencies are less than 100 cm⁻¹. The DZP basis C_s structure of silicocene, for which there are 13 unique atoms, represents one of the largest systems for which SCF harmonic frequency analyses have been reported.

To account for electron-correlation effects, second-order perturbation theory $(MP2)^{27}$ energies were determined using the DZP basis set at the SCF equilibrium geometries for the conformers $C_{2\nu}(e-e)$, $C_{2\nu}(p-p)$, C_s , C_2 , and D_{5d} . In order to assess the reliability of perturbation theory (MP2) to incorporate correctly the effects of electron correlation, configuration interaction energies²⁸ including all single and double excitations

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Table I. Absolute Energies (hartrees) and Relative Energies (kcal/mol) for the (C₅H₅)₂Si Structures Using the STO-3G* and DZd Basis Sets

SCF/STO-3G*a			SCF/DZd ^o		
absolute	relative	negative eigenvalues	absolute	relative	negative eigenvalues
-665.39323	0.0	0	-673.20243	0.0	0
-665.393 26	-0.02	0	-673.20028	1.4	1
-665.33778	34.8	2	-673.17417	16.8	2
-665.33774	34.8	3	-673.17416	16.8	3
-665.379 05	8.9	2	-673.19068	7.4	2
-665.38962	2.3	2	-673.198 09	2.7	2
	absolute -665.393 23 -665.393 26 -665.337 78 -665.337 74 -665.379 05 -665.389 62	absolute relative -665.39323 0.0 -665.39326 -0.02 -665.33778 34.8 -665.33774 34.8 -665.37905 8.9 -665.38962 2.3	SCF/STO-3G*a negative absolute relative eigenvalues -665.39323 0.0 0 -665.39326 -0.02 0 -665.33778 34.8 2 -665.33774 34.8 3 -665.37905 8.9 2 -665.38962 2.3 2	scF/STO-3G*a negative negative absolute relative eigenvalues absolute -665.39323 0.0 0 -673.20243 -665.39326 -0.02 0 -673.20028 -665.33778 34.8 2 -673.17417 -665.33774 34.8 3 -673.17416 -665.37905 8.9 2 -673.19068 -665.38962 2.3 2 -673.19809	SCF/STO-3G** SCF/DZd ^b negative negative absolute relative scf/DZd ^b -665.393.23 0.0 0 -673.202.43 0.0 -665.393.26 -0.02 0 -673.200.28 1.4 -665.337.78 34.8 2 -673.174.17 16.8 -665.337.74 34.8 3 -673.174.16 16.8 -665.379.05 8.9 2 -673.190.68 7.4 -665.389.62 2.3 2 -673.198.09 2.7

^a Energies are given for the geometries optimized at the SCF STO-3G* level of theory. ^b Energies are given for the geometries optimized at the SCF DZd level of theory.

from the reference wave function (CISD) were determined with the DZd basis at the SCF DZd equilibrium geometries. However, it is important to realize that the essentially nonpolarized DZd basis is inappropriate for the inclusion of quantitative dynamic electron-correlation effects. The effects of size-consistency were considered with the Davidson correction²⁹ (CISD+Q) and with the more rigorous coupled-pair functional^{30,31} (CPF) method. In the CISD and CPF computations, the silicon (1s2s2p) and carbon (1s) corelike molecular orbitals remained doubly occupied in all configurations and the corresponding virtual orbitals were deleted. This generated 1 383 321, 1 381 801, 692 253, and 692 249 (C2h) configurations for the C_s , C_2 , C_{2v} , and D_{5d} conformers, respectively. All electrons and molecular orbitals were allowed to be active when determining the MP2 electronic energy. The SCF and MP2 theoretical predictions reported in this study were obtained with the Cambridge Analytic Derivatives Package (CADPAC).32

The DZP basis (210 basis functions) is the smallest basis that has sufficient correlating functions to determine reliably the optimized geometries of the conformers of silicocene at a correlated level of theory. For the simplest electron-correlation method (MP2), we estimate that a single gradient calculation with current state-of-the-art programs and computational facilities (CRAY XMP-48) would take 6 h of cpu time for the C_s conformer, for which 29 unique nuclear coordinates have to be optimized. Due to the cost, this option was not available. Optimization of a D_{5d} structure (in C_{2h} symmetry) would be somewhat less expensive, but in the absence of the MP2 energies for the optimized C_s or C_2 structures, the more expensive MP2 Hessian would be required to determine whether this conformer was a minimum on the potential energy surface. Even then, it would not determine whether this was the global energy minimum. For the other electron-correlation methods mentioned here (CPF, CISD), the cost of such computations would be significantly more expensive. Thus, given the computational facilities at our disposal, the geometries of the silicocene conformers were not optimized at a correlated level of theory.

Energetics of the Six Conformers of (C,H,),Si. The absolute and relative energies of the six conformers predicted at the SCF level with the STO-3G* and DZd basis sets are given in Table I, together with a characterization of each stationary point in terms of the number of negative eigenvalues³³ of the second-derivative matrix. The C_s and C_2 conformers are both minima on the potential energy surface at the STO-3G^{*} level of theory, with the C_s structure being fractionally lower in energy. The more symmetric conformers, however, are high-order transition states having 2 ($C_{2\nu}(e-e)$), 2 ($C_{2\nu}(p-p)$), 2 (D_{5d}), and 3 (D_{5h}) imaginary frequencies, and they lie 2.3, 8.9, 34.8, and 34.8 kcal/mol higher in energy than the C_2 conformer, respectively.

When the DZd basis is considered, the C_2 conformer is the only genuine minimum on the potential energy surface, with the smallest vibrational frequency being only 45 cm⁻¹. The C_s structure is a transition state (one negative eigenvalue of the Hessian). Thus, the STO-3G* and DZd basis sets give a slightly different description of the surface with respect to the C_2 and C_s conformers. Previous studies have shown that due to the inflexibility of a minimal basis set, a STO-3G* potential energy surface may yield more minima than does a larger basis set.³⁴ The $C_{2\nu}(e-e)$, $C_{2\nu}(p-p)$, D_{5d} , and D_{5h} structures are again high-order transition states (2, 2, 2, and 3 negative eigenvalues of the Hessian, respectively). The relative energetics at the SCF DZd level of theory correlates with the characterization of the stationary points, such that the energies rel-

Table II.	Absolute	Energies	(hartrees) a	and Rel	ative Ene	ergies	
(kcal/mol) for the	$(C_5H_5)_2Si$	Structures	Using	the DZP	Basis !	Set

		SCF ^a	MP2 ^b		
structure	absolute	relative	eigenvalues	absolute	relative
$\overline{C_2}$	-673.36278	0.0	1	-674.93640	0.0
C_{s}	-673.363 25	-0.3	0	-674.936 46	-0.04
D _{5d}	-673.34534	10.9	3	-674.943 97	-4.7
$C_{2v}(e-e)$	-673.360 42	1.5	1	-674.948 39	-7.5
$C_{2v}(p-p)$	-673.359 42	2.1	2	-674.943 82	-4.7

^aEnergies are given for the geometries optimized at the SCF DZP level of theory. ^bSingle-point energies determined at the SCF DZP optimized geometries.

ative to the C_2 conformer are all increasingly positive with values of 1.4 (C_s) , 2.7 $(C_{2\nu}(p-p))$, 7.4 $(C_{2\nu}(e-e))$, and 16.8 kcal/mol (D_{5d}, D_{5h}) . It is important to note that the larger DZd basis set has halved the energy difference between the lower symmetry species and the highest symmetry conformers (D_{5d}, D_{5h}) , compared to the STO-3G* basis set results, although the energies of the $C_{2\nu}$ conformers relative to the C_2 structure are little affected.

The energetic results obtained with the largest DZP basis at the SCF DZP optimized geometries are presented in Table II. The zero-point vibrtional energies affect the relative energetics very little and thus are not included in this discussion. At the SCF level of theory, the C_s and C_2 conformers are again very close in energy, with the C, being the lower by 0.3 kcal/mol. In this case, it is the imaginary frequency of 62.8 cm⁻¹ for the C_2 conformer that indicates a breaking of symmetry to C_1 whereas, at the SCF DZd level of theory, it is an imaginary frequency of 142.6 cm⁻¹ for the C_s structure that is associated with a normal mode, which breaks symmetry and leads to a C_1 configuration. This mode could indicate motion toward the C_2 conformer since there is no element of symmetry linking the C_s and C_2 structures. Judging from the small magnitude of the imaginary frequencies, the silicocene potential energy surface appears to be very flat with respect to interconversion between the C_2 and C_2 conformers at both the SCF DZd and SCF DZP levels of theory. The MP2 DZP single-point energies support this hypothesis since the two conformers are separated by only 0.04 kcal/mol.

The energetics of the high-symmetry conformers relative to the lowsymmetry species (C_2, C_s) change significantly at the SCF DZP level of theory when compared to the values determined with the smaller basis sets. For example, the energy difference between the C_2 and D_{5d} conformers decreases significantly from 16.8 (SCF DZd) to 10.9 kcal/mol (SCF DZP). The addition of the polarization functions to the carbon atoms and the larger span of the d functions on the silicon atom offer more flexibility for the highly symmetric D_{5d} π -bonded structure compared to the C_s and C_2 conformers.

The energy difference, $\Delta E(C_{2\nu}(e-e) - C_2)$, also decreases from 7.4 (DZd) to 1.5 kcal/mol (DZP) whereas the energy of the $C_{2\nu}(p-p)$ structure remains consistently at 2-3 kcal/mol above the C_2 structure. Thus the $C_{2v}(e-e)$ conformer is now slightly lower in energy (0.6 kcal/ mol) than the $C_{2\nu}(p-p)$ species. The imaginary frequency for the $C_{2\nu}$ -(e-e) conformer determined with the DZP basis is greatly reduced in magnitude (62.6 cm⁻¹) from the DZd values (194.8 and 176.7 cm⁻¹) in agreement with the energetic results. The $C_{2v}(p-p)$ conformer remains a second-order transition state on going from the DZd to the DZP basis set, with imaginary frequencies of similar magnitude (55.1 and 43.8 cm⁻¹, DZP; 71.1 and 35.2 cm⁻¹, DZd). The D_{5d} conformer is again a highorder transition state at the SCF DZP level of theory, with three negative eigenvalues of the Hessian. A degenerate pair with an imaginary frequency of 105.0 cm⁻¹ represents a motion toward a bent structure, as was the case with the smaller basis sets. The third imaginary mode (frequency 6.0 cm⁻¹) represents a motion that destroys the symmetry relation

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Table III. Absolute Energies (hartrees) and Relative Energies (kcal/mol) for the $(C_5H_5)_2Si$ Structures Using the CPF, CISD, and MP2 Methods with the DZd Basis Set

	CPF ^a		CISD ^a		CISD+Q ^a		MP2 ^a	
	absolute	relative	absolute	relative	absolute	relative	absolute	relative
	-674.204 00	0.0	-673.939 24	0.0	-674.09370	0.0	-674.11335	0.0
C_s	-674.20223	1.1	-673.938 33	0.6	-674.09290	0.5	-674.116 50	-2.0
D_{5d}	-674.178 90	15.8	-673.91511	15.1	-674.07099	14.3	-674.107 48	3.7
$C_{2v}(e-e)$	-674.19311	6.8	-673.930 53	5.5	-674.085 32	5.3	-674.11588	-1.6
<i>C</i> _{2v} (p-p)	-674.198 76	3.3	-673.934 26	3.1	-674.08861	3.2	-674.108 53	3.0

^aSingle-point energies determined at the SCF DZd optimized geometries.

of the two rings. This type of motion is consistent with a C_s minimum. The relative energies of the conformers determined with methods that include electron correlation in conjunction with the DZd basis are presented in Table III, and the MP2 DZP energies are given in Table II. At this point it should be stressed that the DZd basis is not adequately flexible to quantitatively incorporate the effects of dynamic electron correlation but was used to compare the CPF and CISD results with those of MP2. Thus, while we expect that the trends between the various dynamic electron-correlation techniques will be reliably reproduced with the DZd basis,³⁵ the absolute magnitude of the differences will certainly change when a more complete one particle basis set is used. The DZP basis, which includes a set of polarization functions on C and two sets of polarization functions on Si, is probably the smallest basis set that could reliably include the effects of dynamic electron.

Analysis of the relative energies presented in Table III indicates that electron correlation favors the high-symmetry species over the low-symmetry species. For example, the relative energy of the $C_{2v}(e-e)$ conformer $(\Delta E(C_{2v}(e-e) - C_2))$ is lowered by 0.6 (CPF), 1.9 (CISD), 2.1 (CISD+Q), 9.0 (MP2 DZd), and 9.0 (MP2 DZP) kcal/mol from the corresponding SCF prediction. Similarly, the relative energy of the D_{5d} conformer is also lowered, by 1.0 (CPF), 1.7 (CISD), 2.5 (CISD+Q), 13.1 (MP2 DZd), and 15.6 (MP2 DZP) kcal/mol, compared to the SCF values. However, comparison of the DZd results for the different electron-correlation methods suggests that second-order perturbation theory may overestimate the effects of electron correlation. Nevertheless, the trend that favors the high-symmetry species relative to the C_s and C_2 conformers is likely to become more pronounced on increasing the flexibility of the basis set at all the correlated levels of theory. It is the combined effect of the flexible one-particle basis set and electron correlation that predicts the energies of the $C_{2v}(e-e)$, $C_{2v}(p-p)$, and D_{5d} conformers relative to the C_2 species to be -7.5, -4.7, and -4.7 kcal/mol, respectively, at the MP2 DZP level of theory. Although the effect of electron correlation as measured by the CISD/CPF methods is smaller, a small effect is all that is required to make the $C_{2\nu}(e-e)$ conformer a minimum on the potential energy surface, since at the SCF DZP level of theory, the difference in energy between the $C_{2v}(e-e)$ and C_s conformers is only 1.8 kcal/mol. It should be reiterated that the small DZd basis set may considerably underestimate the effects of dynamic electron correlation, due to the lack of correlating functions.³⁵ Thus, the only conclusion that can be drawn from the energetic results of Table III is that MP2 probably overestimates the effects of electron correlation, but the magnitude of this overestimation is not discernable. These results do suggest that a conformer adopting higher symmetry than C_2 or C_s may be the minimum energy gas-phase structure of $(C_5H_5)_2Si$. Such a result would be consistent with the experimental findings for decamethyl silicocene, $(C_5Me_5)_2Si$, and would demonstrate that the D_{5d} symmetry of decamethyl silicocene is due in part to the electronic structure and not solely the repulsive steric interaction of the methyl groups.

Highly accurate relative energies of the conformers of (C5H5)2Si are difficult to predict given the obvious importance of electron correlation. Full-geometry optimization at a correlated level of theory followed by an analytic second-derivative determination will possibly lead to a different global minimum energy structure. Such determinations would require large basis sets of triple-5 plus double-polarization quality to be quantitative, and although current theoretical methods are capable of full-geometry optimizations at the MP2 DZP level of theory, the cost and available computational facilities make them impractical. Because both basis set augmentation and electron correlation favor the high-symmetry conformers of silicocene, experience²¹⁻²⁵ suggests that the gas-phase minimum energy structure adopts D_{5d} , D_{5h} , or at least C_{2v} symmetry. However, since a vast quantity of ab initio results on molecules of this size do not exist, we feel that the only definitive conclusion that may be drawn is that the silicocene potential energy surface is very flat with respect to movement of the two Cp rings.

Table IV. Predicted Geometrical Parameters for the C_s Structure of $(C_sH_5)_2Si^{\alpha}$

	STO-3G*	DZd	DZP
Si-ring 1 centroid (X_1)	2.701	2.661	2.534
Si-ring 2 centroid (X_2)	2.124	2.345	2.266
X_1 -Si- X_2 angle θ	149.2	149.1	152.4
ring normal–Ši–ring normal angle ϕ	72.7	74.7	89.3
angle between Cp rings	107.3	105.3	90.7
	Si-C Distand	ces ^b	
$Si-C_6(C_3)$	1.911 (2.880)	1.969 (3.127)	2.003 (2.992)
$Si-C_4$ (C ₂)	2.755 (2.585)	2.732 (2.803)	2.650 (2.704)
$Si-C_5(C_1)$	3.539 (2.016)	3.467 (2.158)	3.269 (2.159)
$Si-C_{5'}(C_{1'})$	3.539 (2.016)	3.467 (2.158)	3.269 (2.159)
$Si-C_{4'}(C_{2'})$	2.755 (2.585)	2.732 (2.803)	2.650 (2.704)
	C-C Distanc	ces ^b	
C ₆ -C ₄	1.512 (1.391)	1,496 (1,404)	1.475 (1.398)
C ₄ -C ₅	1.326 (1.415)	1.358 (1.421)	1.357 (1.414)
C ₅ -C _{5'}	1.475 (1.459)	1.460 (1.460)	1.447 (1.442)
C ₅ -C ₄	1.326 (1.415)	1.358 (1.421)	1.357 (1.414)
C ₄ -C ₆	1.512 (1.391)	1.496 (1.404)	1.475 (1.398)
	C-H Distand	ces ^b	
C₄−H	1.087 (1.078)	1.081 (1.068)	1.081 (1.073)
C₄-H	1.081 (1.083)	1.071 (1.069)	1.075 (1.074)
C ₄ -H	1.081 (1.077)	1.070 (1.070)	1.075 (1.074)
Č,́~H	1.081 (1.077)	1.070 (1.070)	1.075 (1.074)
C₄~-H	1.081 (1.083)	1.071 (1.069)	1.075 (1.074)

^aBond lengths are given in angstroms and angles in degrees. See Figure 1 for the numbering of the carbon atoms. ^bValues in parentheses refer to the second ring.

Table V. Predicted Geometrical Parameters for the C_2 Structure of $(C_5H_5)_2Si^a$

	STO-3G*	DZd	DZP
Si-ring centroid (X)	2.615	2.576	2.386
X-Si-X angle θ	142.8	146.6	152.3
ring normal–Si–ring normal angle φ	51.3	64.7	90.2
angle between Cp rings	128.7	115.3	89.8
Si-G	C Distances		
Si-C ₁	3.483	3.417	3.131
Si-C ₂	2.784	2,792	2.675
Si-C ₃	1.887	1.967	2.032
Si-C ₄	2.589	2.542	2.403
Si-C ₅	3.383	3.287	2.980
C-(C Distances		
$C_1 - C_2$	1.328	1.361	1.368
$C_{2} - C_{3}$	1.506	1.484	1.455
C ₃ -C ₄	1.515	1.497	1.461
C ₄ -C ₅	1.329	1.365	1.375
$C_5 - C_1$	1.472	1.455	1.431
C-H	H Distances		
C ₁ -H	1.080	1.069	1.074
C ₂ -H	1.081	1.070	1.074
C₁−H	1.087	1.080	1.078
C₄-H	1.081	1.071	1.074
C ₅ -H	1.082	1.070	1.075

^aBond lengths are given in angstroms and angles in degrees. See Figure 2 for the numbering of the carbon atoms.

The possibility of silicocene possessing a triplet ground state was also investigated. However, the highest occupied molecular orbital and the

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Figure 1. Pictorial representation of the C_s conformer of silicocene. Note that the two cyclopentadienyl rings are not symmetry related in this isomer. Symmetry-related atoms are primed.



Figure 2. Pictorial representation of the C_2 conformer of silicocene. Note that the two cyclopentadienyl rings are symmetry related in this isomer. Symmetry-related atoms are primed.

lowest unoccupied molecular orbital for the high-symmetry conformers are both doubly degenerate and so such a triplet state would have to distort to lower symmetry by the Jahn-Teller theorem. Test SCF energies with the DZd basis set for the low-symmetry triplet states were at least 80 kcal/mol higher in energy than the lowest SCF singlet. Therefore, further investigations of triplet states were deemed unnecessary.

Structures of the Six Conformers of $(C_5H_5)_2$ Si. The geometric parameters for the C_s and C_2 conformers of silicocene are given in Tables IV and V, respectively. For these species, the cyclopentadienyl plane was defined as the "best" plane in terms of a least-squares fit of the carbon atom positions. This procedure was used previously for the structural analysis of the phosphocenium cation.¹³ Also note that X defines the centroid of these least-squares fit planes. The greek letter θ represents the angle X_1 -Si- X_2 or ring one centroid-Si-ring two centroid. The angle ϕ is defined as the supplement to the angle between the two Cp rings. See Figure 1 for the numbering of the carbon atoms of the C_2 isomer.

Considering first the C_s and C_2 conformers, it is evident that as the basis set is improved the two cyclopentadienyl rings become less skewed toward one another, approaching a more symmetric structure. Two independent structural parameters support this conclusion. The angle θ increases from 149.2° (STO-3G*) to 152.4° (DZP) and from 142.8° (STO-3G*) to 152.3° (DZP) for the C_s and C_2 conformers, respectively. Even more significant, though, is the large decrease in the angle between the Cp rings. For the C_s structure this angle ranges from 107.3° (STO-3G*) to 105.3° (DZd) to 90.7° (DZP). The C_2 species exhibits an even larger change, with this angle varying from 128.7° (STO-3G*) to 115.3°



Figure 3. Pictorial representation of the $C_{2\nu}(e-e)$ conformer of silicocene. Note that the two cyclopentadienyl rings are symmetry related in this isomer. Symmetry-related atoms are primed.



Figure 4. Pictorial representation of the $C_{2\nu}(p-p)$ conformer of silicocene. Note that the two cyclopentadienyl rings are symmetry related in this isomer. Symmetry-related atoms are primed.

(DZd) to 89.8° (DZP). Note, that for both conformers the addition of polarization functions on the carbon atoms and two sets of polarization functions on the silicon atom is vitally important for the proper determination of this angle.

A second interesting basis set effect is the decrease in the range of the Si-C bond distances as the basis is improved. When the STO-3G* basis is used, the C_s conformer Si-C bond distances range from 1.911 to 3.539 Å for one cyclopentadienyl ring and 2.016 to 2.880 Å for the other, while for the C_2 conformer the Si-C bond distances range from 1.887 to 3.483 A (two equivalent rings). The analogous DZP results are 2.003-3.269 and 2.159-2.992 Å for the C_s structure and 2.032-3.131 Å for the C_2 species. The reduction in the range of the Si-C bond distances together with the decrease in the angle between the Cp rings is indicative of a movement toward a more symmetric structure. When Tables IV and V are examined, it is also evident that the greatest reduction in the range of Si-C distances occurs between the DZd and DZP basis sets, again emphasizing the importance of polarization functions for the proper description of sandwich compounds. After making the above observations, it should not be surprising that the range of C-C bond distances also decreases in going from the STO-3G* basis set to the much larger DZP basis. In particular, the range of C-C bond distances decreases from 1.328–1.515 (STO-3G*) to 1.368–1.461 Å (DZP) for the C_2 conformer.

Another interesting feature of the $(C_5H_5)_2$ Si potential energy surface is the similarity between the C_s and C_2 structures with increasing theoretical sophistication. For example, the angle θ takes the values 149.1° and 146.6° with the DZd basis for the C_s and C_2 structures, respectively. However, with the larger DZP basis, θ has the values 152.4° and 152.3°, respectively. A better example is given by the angle between the Cp rings where the appropriate values are 105.3° (C_s ; DZd), 115.3° (C_2 , DZd),

Table VI. Predicted Geometrical Parameters for the $C_{2v}(e-e)$ Structure of $(C_5H_5)_2Si^a$

	STO-3G*	DZd	DZP					
Si-ring centroid (X)	2.118	2.337	2.260					
X_1 -Si- X_2 angle θ	155.6	152.5	153.5					
ring normal-Si-ring normal angle ϕ	108.1	103.0	112.3					
angle between Cp ring	s 71.9	77.0	67.7					
	Si-C Distances							
Si-C ₁	2.815	3.034	2.901					
Si-C ₂	2.560	2.764	2.670					
Si-C ₃	2.073	2.236	2.239					
	C-C Distances							
$C_1 - C_2$	1.391	1.406	1.400					
$C_2 - C_3$	1.411	1.420	1.413					
$C_{3} - C_{3'}$	1.448	1.450	1.433					
C-H Distances								
C ₁ -H	1.078	1.068	1.074					
C ₂ -H	1.081	1.069	1.074					
<u>С</u> ₃ -Н	1.076	1.069	1.073					

^aBond lengths are given in angstroms and angles in degrees. See Figure 3 for the numbering of the carbon atoms.

Table VII. Predicted Geometrical Parameters for the $C_{2v}(p-p)$ Structure of $(C_5H_5)_2Si^a$

	STO-3G*	DZd	DZP						
 Si-ring centroid (X)	2.635	2.594	2.297						
X_1 -Si- X_2 angle θ	152.1	156.5	158.4						
ring normal-Si-ring normal angle φ	58.8	76.2	112.2						
angle between Cp rings	121.2	103.8	67.8						
Si-C	Distances								
Si-C ₁	1.893	1.978	2.119						
Si-C ₂	2.704	2.677	2.474						
Si-C ₃	3.458	3.356	2.899						
C-C Distances									
$C_1 - C_2$	1.511	1.490	1.436						
$C_2 - C_3$	1.328	1.364	1.392						
$C_{3} - C_{3'}$	1.472	1.451	1.410						
C-H	Distances								
C ₁ -H	1.086	1.078	1.073						
C ₂ -H	1.081	1.071	1.074						
C ₃ -H	1.081	1.070	1.073						
-									

^aBond lengths are given in angstroms and angles in degrees. See Figure 4 for the numbering of the carbon atoms.

90.7° (C_s ; DZP), and 89.8° (C_2 ; DZP). Further evidence suggesting the increasing similarity of the C_2 and C_s conformers is given by the decrease in the magnitude of the imaginary frequency of the transition state with basis set improvement. Specifically, the imaginary frequency with the DZd basis is 142.6 cm⁻¹ (C_s conformer) while with the DZP basis set it is only 62.8 cm⁻¹ (C_2 conformer).

The geometric parameters for the $C_{2\nu}$ conformers are given in Tables VI and VII. See Figures 3 and 4 for the numbering of the carbon atoms. The two $C_{2\nu}$ structures show markedly dissimilar behavior with respect to augmentation of the basis set. Like the lower symmetry structures, the $C_{2\nu}(p-p)$ conformer exhibits a large decrease in the angle between Cp rings (121.2°, STO-3G*; 67.8°, DZP), a reduction on the range of Si-C distances (1.565 Å, STO-3G*; 0.780 Å, DZP), and a reduction in the range of C-C bond lengths (0.183 Å, STO-3G*; 0.044 Å, DZP). Note that these trends are again indicative of movement toward a more

symmetric structure. The structural parameters of the $C_{2v}(e-e)$ conformer do not change significantly on going from the STO-3G* basis to the DZP basis, unlike those for the $C_{2v}(p-p)$ conformer. However, the DZP geometries of both the C_{2v} conformers show many similarities. For example, both have a very similar angle between ring planes (67.7°, $C_{2v}(e-e)$; 67.8°, $C_{2v}(p-p)$), range in Si-C distances (0.780 Å, $C_{2v}(p-p)$; 0.662 Å, $C_{2v}(e-e)$), and range in C-C bond lengths (0.044 Å, $C_{2v}(p-p)$; 0.030 Å, $C_{2v}(e-e)$).

Although the $C_{2\nu}(p-p)$ equilibrium structure changes significantly with respect to basis set enlargement, its energy relative to the lowest symmetry conformers does not change dramatically. Conversely, the $C_{2\nu}(e-e)$ equilibrium structure is little affected by improvements in the basis set, but the relative energetics are considerably altered on going from the DZd to the DZP basis set. This may be understood by considering the angle between ring planes determined for the $C_{2\nu}(e-e)$, $C_{2\nu}(p-p)$, and C_2 conformers with the DZd and DZP basis sets. The difference between this angle for the $C_{2\nu}(p-p)$ and C_2 conformers is 11.5° and 22.0° for the DZd and DZP basis sets, respectively, whereas the corresponding differences between the $C_{2\nu}(e-e)$ and C_2 conformers are 38.3° (DZd) and 22.1° (DZP). The larger relative change and the direction of the change for the $C_{2\nu}(e-e)$ conformer could thus explain the drop of 5.9 kcal/mol between the relative energies of the $C_{2\nu}(e-e)$ and C_2 structures on going from the DZd to the DZP basis set.

The structural similarities between the $C_{2\nu}(e-e)$ and $C_{2\nu}(p-p)$ conformers at the DZP level results in the imaginary frequencies of the two structures now having the same order of magnitude (62.6 cm⁻¹, $C_{2\nu}(e-e)$; 71.1 and 35.2 cm⁻¹, $C_{2\nu}(p-p)$), corresponding to motions to a lower symmetry structure (62.6 and 71.1 cm⁻¹) and to a "pseudorotation" of one ring relative to the other for the $C_{2\nu}(p-p)$ conformer (35.2 cm⁻¹). Furthermore, the energetics determined at the SCF DZP level of theory show that the $C_{2\nu}(c-e)$, and $C_{2\nu}(p-p)$ conformers lie within a range of 2.4 kcal/mol, indicating that the potential surface is very flat in this region.

The D_{5h} and D_{5d} optimized structural parameters are listed in Table VIII. The obvious difference between the high-symmetry species and the lower symmetry conformers is the large reduction in the number of independent nuclear degrees of freedom. Namely, the D_{5h} and D_{5d} structures have only four unique nuclear coordinates as compared to the C_s and C_2 conformers, which have 29 unique coordinates.

The most notable basis set effect found for the D_{5h} and D_{5d} conformers is the increase in the Si-C distance. In particular, the Si-C distance changes from 2.339 (STO-3G*) to 2.523 Å (DZP) for the D_{5d} species. However, this increase is due to the larger s,p basis set as shown by the slight decrease in the Si-C distance in going from the DZd (2.568 Å) to the DZP (2.523 Å) basis set. This parameter may alternatively be represented by the Si-ring centroid distance, 2.010 (STO-3G*), 2.266 (DZd), and 2.219 Å (DZP).

For comparison, the D_{5d} MNDO optimized structural parameters¹⁴ of $(C_5H_5)_2Si$ and the reported structural parameters¹² of $(C_5Me_5)_2Si$ are also listed in Table VIII. The MNDO structure is quite different from the DZP ab initio structure, with the Cp rings being significantly closer to the silicon atom yielding a Si-C distance of only 2.198 Å. The DZP SCF Si-C and Si-X distances are quite similar to those determined experimentally for the full methyl derivative. For both quantities, the ab initio values are approximately 0.1 Å larger. The ab initio and experimental C-C bond lengths are not as comparable since the experimental value represents an average of the D_{5d} and bent structures.

Bonding in $(C_5H_5)_2Si$. Labeling a cyclopentadienyl ring as η , η^2 , or η^n bonded to the central silicon atom is necessarily somewhat arbitrary. One standard of comparison would be to compare a typical Si-C bond length with the Si-C distances in $(C_5H_5)_2Si$. This method was utilized in the study of the phosphocenium cation.¹³ However, from comparison of the experimental Si-C bond length in methylsilane, H₃CSiH₃, of 1.867 Å^{36,37} and the corresponding SCF DZP value of 1.880 Å³⁸ with the

Table VIII. Predicted Geometrical Parameters for D_{5h} and D_{5d} Structures of $(C_5H_5)_2Si^a$

		50 54	,	5 5.2			
	STO-3G*		D	DZd		MNDO ^b	expt ^c
	$\overline{D_{5h}}$	D_{5d}	D _{5h}	D _{5d}	D_{5d}	D _{5d}	D_{5d}
Si-ring centroid (X)	2.010	2.010	2.266	2.267	2.219	1.826	2.11
Si-C distance	2.339	2.339	2.568	2.568	2.523	2.198	2.42
C-C distance	1.405	1.405	1.419	1.419	1.410	1.438	1.394
C-H distance	1.078	1.078	1.068	1.068	1.074		
Si-X-H angle	89.4	89.4	90.7	90.7	90.1		

^aBond lengths are given in angstroms and angles in degrees. ^bFrom ref 15. ^cExperimental data for decamethyl silicocene from ref 12.

Table IX. Mulliken Orbital Populations of the Silicon Atom in the C_s , C_2 , and D_{5d} Conformers of $(C_5H_5)_2$ Si Using the DZP Basis Set

J. L.	50								
	C,	<i>C</i> ₂	$C_{2v}(e-e)$	C _{2v} (p-p)	D_{5d}				
s	5.98	5.98	6.01	6.00	6.00				
$p_r + p_v$	5.13	5.15	5.09	5.09	4.86				
p,	2.38	2.35	2.30	2.33	2.29				
d	0.08	0.08	0.17	0.15	0.34				
Total Atomic Population									
Si	13.57	13.56	13.58	13.57	13.51				

experimental Si-C distance in decamethyl silicocene (2.42 Å), this approach seems inappropriate in this case. An alternative method would be to use the Si-C distance of the SCF DZP high-symmetry D_{5d} conformer as the standard of comparison, since this structure certainly exhibits η^5 bonding between the Cp rings and the central silicon atom. This distance defined by the SCF DZP level of theory is within 0.1 Å of the experimental determination for $(C_5Me_5)_2Si$. Therefore, we discuss the bonding in the C_s , C_2 , and $C_{2\nu}$ conformers based on an upper limit of 2.523 Å, the Si-C distance for the D_{5d} conformer (SCF DZP). The C_2 structure is then defined to have η^2 bonding to each ring (Si-C = 2.03 and 2.40 Å) comparable to the C_2 conformer of $(C_5H_5)_2P^+$. The C_s structure exhibits η bonding to one ring (Si-C = 2.00 Å) and η^2 bonding to the other ring (Si-C = 2.16 and 2.16 Å), similar to the C_s conformers of $(C_5H_5)_2P^+$ and $(C_5Me_5)_2As^+$. Both rings of the C_2 structure and the ring of the C_3 structure, which is η bonded to the Si atom and most closely approaches the Si atom via a unique carbon atom, display a reasonable degree of alternation of C-C bond lengths, namely, 1.455, 1.368, 1.431, 1.375, and 1.461 Å for the C_2 conformer and 1.475, 1.357, 1.447, 1.357, and 1.475 Å for the C_s conformer. The second ring of the C_s conformer, which is η^2 bonded to the silicon atom, displays much less bond alternation. We note, however, that if the SCF STO-3G* C-C bond lengths were used in this analysis, then a different picture of the bonding in the cyclopentadienyl rings would emerge. Namely, there is significantly greater bond alternation in these rings, leading to a view of the cyclopentadienyl rings as having very localized single and double bonds. Therefore, it is important to stress the necessity of using large basis sets in ab initio studies of loosely bound π -bonded complexes in order to obtain a reliable description of the bonding.

On the basis of our model, the $C_{2\nu}(e-e)$ conformer exhibits η^2 bonding to each Cp ring (Si-C = 2.24 and 2.24 Å) while the $C_{2v}(p-p)$ structure shows η^3 bonding to each Cp ring (Si-C = 2.12, 2.47, and 2.47 Å), similar to the analogous conformers of the phosphocenium cation.¹³ The C-C bonding in the rings of the $C_{2\nu}$ conformers is much more equivalent than for the C_2 and C_3 conformers, with a maximum range of 0.044 Å. Moreover, the average C-C distance in the C_{2v} structures (1.413 Å, $C_{2v}(p-p)$; 1.412 Å, $C_{2v}(e-e)$) closely approaches the C-C bond distance in the D_{5d} conformer (1.410 Å). Thus, the Cp rings are best viewed as having a delocalized π structure around the ring.

Comparing the DZP SCF Si-C distances for the C_s , C_2 , and $C_{2\nu}$ structures with the Si-C distance for the D_{5d} conformer, we note that the C_{2v} , C_2 , and C_s conformers exhibit maximum deviations of 16, 24, and 30%, respectively. Therefore, it should not be surprising that the C_{2v} conformers exhibit a greater degree of π bonding to the Cp rings. As a final note concerning the extent of π bonding present in the different silicocene conformers, we point out that had this analysis been performed with only the SCF STO-3G* data, different conclusions would have resulted. For example, the $C_{2v}(p-p)$ structure would have been labeled as η bonded for each Cp ring. Therefore, we again emphasize the necessity of including in the basis set a minimum of one set of polarization functions on the carbon atom and two sets of polarization functions on the silicon atom.

Mulliken population analyses are reported in Table IX for the C_s , C_2 , $C_{2\nu}(e-e)$, $C_{2\nu}(p-p)$, and D_{5d} conformers at the SCF DZP level of theory. It must be realized that these values are somewhat arbitrary since they are based on a nonunique partitioning scheme;³⁹ however, the trends between the different isomers at the same level of theory should be reproducible and give insight into the bonding present in the different conformers of silicocene. On the basis of the data in Table IX, it is clear that the relative importance of d functions changes between the various isomers. As the system becomes more symmetric, the d function population increases: 0.08 (C_s), 0.08 (C₂), 0.15 (C_{2v}(p-p)), 0.17 (C_{2v}(e-e)), and 0.34 (D_{5d}) . It is well established that silicon has energetically lowlying d orbitals, and from these studies it would appear that symmetric structures allow more d function participation in the bonding. Electron correlation should also favor the highly symmetric forms since inclusion of electron-correlation effects generally increases the polarization function participation in the molecular bonding.

Comparison of the total silicon electron populations, which are 13.57 (C_s) , 13.56 (C_2) , 13.58 $(C_{2v}(e-e))$, 13.57 $(C_{2v}(p-p))$, and 13.51 (D_{5d}) , shows that the moderate amount of charge transfer from the silicon atom to the two Cp rings remains fairly constant for all the structures and, therefore, should not have a large differential effect on the conformations of $(C_5H_5)_2Si$.

Concluding Remarks

We have presented results of the first ab initio study of the dicyclopentadienyl sandwich compound silicocene. The simplest ab initio method (SCF STO-3G*) predicts silicocene to adopt a low-symmetry, bent structure. The trends in energetics on increasing the basis set from STO-3G* to DZP at the SCF level for the C_s , C_2 , and C_{2v} conformers of silicocene indicate that the effect of enlarging the basis set stabilizes the C_{2v} conformers relative to the C_s and C_2 conformers. There is also a dramatic lowering in energy of the D_{5d} structure relative to the C_s and C_2 structures.

Accepting that a unique partitioning scheme for the atomic orbital analysis of SCF electronic wave functions does not exist and that any method used is in some way biased, we have performed atomic orbital population analyses of the DZP SCF electronic wave functions using the well-known Mulliken approach. These analyses demonstrate that the Si d orbital population of the D_{5d} and C_{2v} symmetry species is larger than for the C_s and C_2 conformers. Thus, since the symmetric conformers have more silicon d orbital participation in the bonding, this trend in energetics is likely to continue with augmentation of basis set, particularly including a complete span of polarization functions. Furthermore, the effects of dynamic electron correlation appear to lower the symmetric species relative to the C_2 and C_s conformers. Thus, the reason silicocene may adopt a high-symmetry conformation is due to the low-lying d orbitals of silicon and because the more symmetric structures increase the Si d orbital participation in the bonding

Although, the C_{2v} structures are closer energetically to the C_2 and C_s structures, the geometric parameters show many similarities with a more highly symmetric species. For the $C_{2v}(e-e)$ conformer, the range in Si-C distances is much reduced from that determined for the C_2 and C_s conformers and lies within 15% of the D_{5d} Si-C bond distance with an associated range in C-C bond lengths of only 0.030 Å. It remains to be seen whether the effects of larger basis sets and electron correlation will reduce the angle between ring planes by the 68° required to make the D_{5d} or D_{5h} conformer a global energy minimum on the potential energy surface.

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